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PTO-1595	F		SHEET U.S. DEPARTMENT OF COMMER Patent and Trademark Off
To the Honorable Commission	ner of Patents and Trauemans	46	attached original documents or copy thereof.
1 Name of conveying party(i	es):	2 Name a	and address of receiving party(ies):
Lain-Jong Li Chung-Chi Ko	9-19-02	No. 12 Scienc	n Semiconductor Manufacturing Co. Ltd 21 Park Avenue 3 ce-Based Industrial Park Chu, Taiwan, R.O.C.
3 Nature of conveyance: ■ Assignment □ Security Agreement □ Other: Execution Date: August	☐ Merger☐ Change of Name 1, 2002	Additiona	Chu, Taiwan, R.O.C.
4 Application number(s) or pa	atent number(s): 1/0///	095	
If this document is being fil	ed together with a new application	o 🕽 🔾 , the execution	date of the application is: <u>08-01-02</u>
A. Patent Application No(s	s).	B. Pater	nt No(s)
	Additional numbers att	<mark> </mark> ached? □ Yes	s ⊠ No
Name and address of party to whom correspondence concerning document should be mailed: RANDY W. TUNG Tung & Associates 838 W. Long Lake Road Suite 120 Bloomfield Hills, Michigan 48302		6 Total number of applications and patents involved: 1	
		0	Enclosed Authorized to charge credit card (w/filling fee)
			Account Number: 50-0484
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9 Statement and signature. To the best of my knowledg the original document. Randy W. Tung Name of Person Signing Registration No. 31,311	se and belief, the foregoing information of the Signature	ition is true and	d correct and any attached copy is a true copy of September 19, 2002 Date
			ding cover sheet, attachments, and document : 3
Mail d 002 GGEBREGI 00000040 10246895	locuments to be recorded with r Commissioner of Patents & Tra Washington,	ademarks, Bo	· sheet information to: x Assignments

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PATENT REEL: 013310 FRAME: 0688

ASSIGNMENT

WHEREAS, we, <u>LAIN-JONG LI AND CHUNG-CHI KO</u> have invented certain improvements in METHOD FOR FORMING LOW DIELECTRIC CONSTANT DAMASCENE STRUCTURE WHILE EMPLOYING A CARBON DOPED SILICON OXIDE CAPPING LAYER for which we are about to make application for Letters Patent of the United States; and

WHEREAS, TAIWAN SEMICONDUCTOR MANUFACTURING CO., LTD. of No. 121, Park Avenue 3, Science-Based Industrial Park, Hsin-Chu, Taiwan, R.O.C, is desirous of acquiring the entire right, title and interest in and to said invention;

NOW, THEREFORE, in consideration of One Dollar (\$1.00) and other good and valuable consideration, the receipt of which is hereby acknowledged, we, LAIN-JONG LI AND CHUNG-CHI KO, by these presents, do hereby sell, assign and transfer unto the said corporation and its assigns, for the territory of the United States of America and all foreign countries, the entire right, title and interest, including all priority rights under the International Convention associated with each country of the Union, in and to said invention as described in the patent application executed by us on the __/_St_ day of _________, 2002, preparatory to obtaining Letters Patent of the United States thereon, and in and to said application and any Letters Patent that may be granted in pursuance of said application and any divisional, continuation or continuation-in-part

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application thereof, and in and to any reissue of any such patent, and in and to any patent applications which may be filed on said invention in countries foreign to the United States and any Letters Patent granted thereon.

We further authorize said corporation to apply for foreign patents on said invention in its own name or through its designees, including subsidiaries, related companies or assignees, under the International Convention or otherwise, and we further agree to execute all papers, including those required for the United States and foreign applications, and to perform such other proper acts as said corporation or its designees the rights herein assigned.

Lain-JUNG L. Change (L. ter

TUNG & ASSOCIATES 838 W. Long Lake Road Suite 120 Bloomfield Hills, Michigan 48302

RECORDED: 09/19/2002